## NSN 5961-01-526-7805

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-526-7805 **Inclosure Material:** Plastic and metal **Overall Length:** 3.386 inches **Overall Height:** 1.220 inches **Overall Width:** 2.441 inches **End Application:** 9power unit, 2kva, ups 832-01a; power unit, 2kva, ups 832-01b; power unit, 3kva, ups 833-01d; power unit, 3kva, ups 833-01c; 0.8kw, dc 841-01; power unit, 1kva, ac 831-01; power unit, 2.4kw, dc 831-01; power unit, 3kva, ups 833-01b; power unit, 3kva, ups 833-01a **Mounting Facility Quantity:** 4 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 repetitive peak reverse voltage and 640.0 off-state voltage, dc **Current Rating Per Characteristic:** 2.00 amperes zero-gate-voltage source current horsepower metric **Power Rating Per Characteristic:** 0.5 watts small-signal input power, common-collector universal **Product Name:** Three-phase scr/diode bridge module **Terminal Type And Quantity:** 5 screw and 5 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: